

SOT23 PNP SILICON PLANAR DARLINGTON TRANSISTORS

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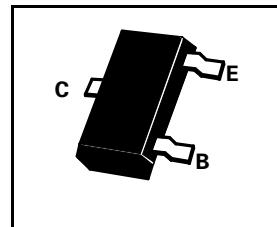
**BCV26
BCV46**

FEATURES

- * Low saturation voltage

COMPLEMENTARY TYPE – BCV26 - BCV27
BCV46 - BCV47

PARTMARKING DETAILS – BCV26 - ZFD
BCV46 - ZFE



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	BCV26		BCV46	UNIT
Collector-Base Voltage	V_{CBO}		-40	-80	V
Collector-Emitter Voltage	V_{CEO}		-30	-60	V
Emitter-Base Voltage	V_{EBO}			-10	V
Peak Pulse Current	I_{CM}			-800	mA
Continuous Collector Current	I_C			-500	mA
Base Current	I_B			-100	mA
Power Dissipation at $T_{amb}=25^\circ\text{C}$	P_{tot}			330	mW
Operating and Storage Temperature Range	$T_j:T_{stg}$			-55 to +150	°C

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ\text{C}$ unless otherwise stated).

PARAMETER	SYMBOL	BCV26		BCV46		UNIT	CONDITIONS.
		MIN.	MAX.	MIN.	MAX.		
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-40		-80		V	$I_C=100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-30		-60		V	$I_C=10\text{mA}$ *
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-10		-10		V	$I_E=10\mu\text{A}$
Collector Cut-Off Current	I_{CBO}		-100 -10		-100 -10	nA nA μA μA	$V_{CB}=-30\text{V}$ $V_{CB}=-60\text{V}$ $V_{CB}=-30\text{V}, T_{amb}=150^\circ\text{C}$ $V_{CB}=-60\text{V}, T_{amb}=150^\circ\text{C}$
Emitter Base Cut-Off Current	I_{EBO}		-100		-100	nA	$V_{EB}=-4\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$		-1.0		-1.0	V	$I_C=-100\text{mA}, I_B=-0.1\text{mA}$ *
Base-Emitter Saturation Voltage	$V_{BE(\text{sat})}$		-1.5		-1.5	V	$I_C=-100\text{mA}, I_B=-0.1\text{mA}$ *
Static Forward Current Transfer Ratio	h_{FE}	4K 10K 20K 4K		2K 4K 10K 2K			$I_C=100\mu\text{A}, V_{CE}=-1\text{V}$ † $I_C=10\text{mA}, V_{CE}=-5\text{V}$ * $I_C=100\text{mA}, V_{CE}=-5\text{V}$ * $I_C=500\text{mA}, V_{CE}=-5\text{V}$ *
Transition Frequency	f_T	200 Typical		200 Typical		MHz	$I_C=50\text{mA}, V_{CE}=-5\text{V}$ $f=20\text{MHz}$
Output Capacitance	C_{obo}	4.5 Typical		4.5 Typical		pF	$V_{CB}=-10\text{V}, f=1\text{MHz}$

*Measured under pulsed conditions. Pulse width=300μs. Duty cycle ≤2%

Spice parameter data is available upon request for these devices

† Periodic Sample Test Only.